

January 2016

# FPF1203 / FPF1203L / FPF1204 / FPF12045 IntelliMAX™ Ultra-Small, Slew-Rate-Controlled Load Switch

#### Features

- 1.2 V to 5.5 V Input Voltage Operating Range
- Typical R<sub>ON</sub>:
  - 45 mΩ at V<sub>IN</sub>=5.5 V
  - 55 mΩ at V<sub>IN</sub>=3.3 V
  - 90 mΩ at V<sub>IN</sub>=1.8 V
  - 185 mΩ at V<sub>IN</sub>=1.2 V
- Slew Rate Control with t<sub>R</sub>:
  - FPF1203/FPF1203I/FPF1204: 100 μs
  - FPF12045: 2 µs
- Output Discharge Function on FPF1204 / 45
- Low <1.5 µA Quiescent Current
- ESD Protected: Above 7 kV HBM, 2 kV CDM
- GPIO / CMOS-Compatible Enable Circuitry
- 4-Bump, WLCSP 0.76 mm x 0.76 mm, 0.4 mm Pitch

#### Applications

- Mobile Devices and Smart Phones
- Portable Media Devices
- Tablet PCs
- Advanced Notebook, UMPC, MID
- Portable Medical Devices
- GPS and Navigation Equipment

#### Switch **ON Pin** Output Top (Typical) Package t<sub>R</sub> Part Number Mark Discharge Activity at 3.3V<sub>IN</sub> FPF1203UCX QL $55 \text{ m}\Omega$ NA Active HIGH 100 µs QΡ NA FPF1203LUCX $55 \text{ m}\Omega$ Active LOW 100 µs 4-Bump, Wafer-Level Chip-Scale 100 µs 65 Ω Active HIGH FPF1204UCX QM $55 \text{ m}\Omega$ Package (WLCSP), 0.76 mm x FPF1204BUCX 0.76 mm, 0.4 mm Pitch QM 55 mΩ 65 Ω Active HIGH 100 µs (Backside Laminate) FPF12045UCX NC $55 \text{ m}\Omega$ 65 O Active HIGH 2 µs

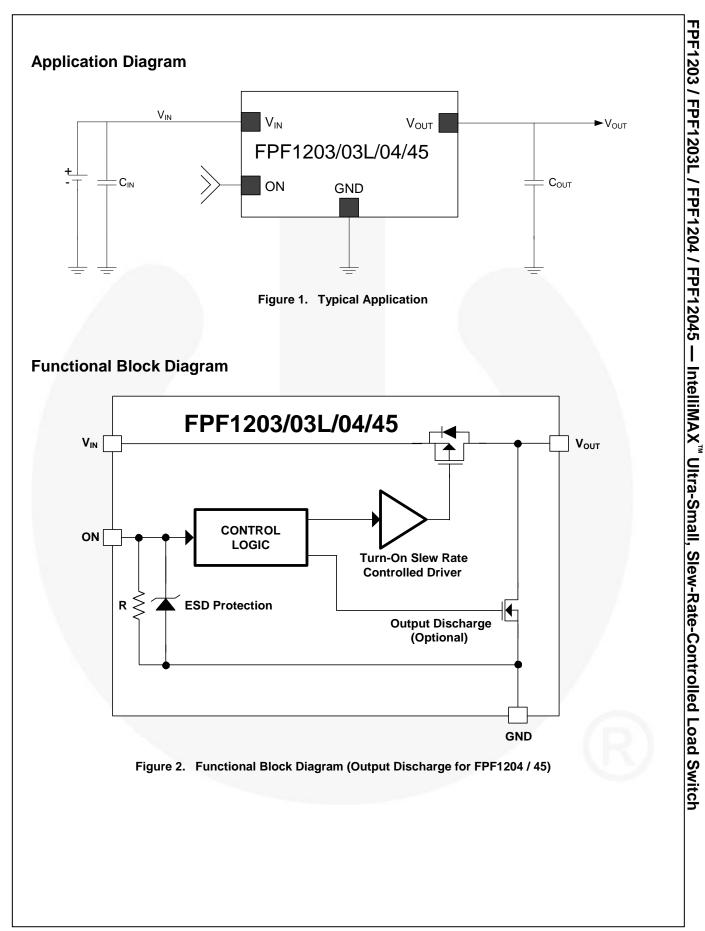
### **Ordering Information**

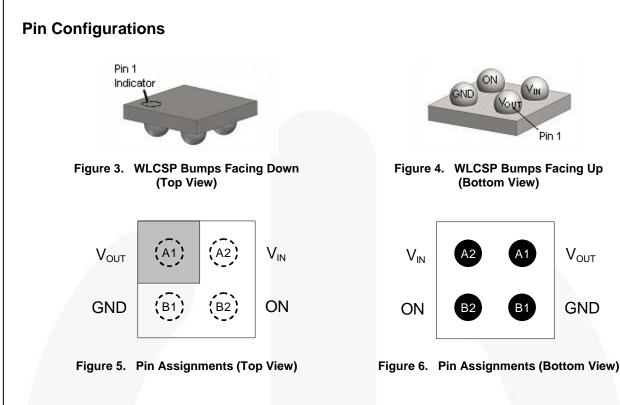
© 2011 Fairchild Semiconductor Corporation FPF1203 / FPF1203L / FPF1204 / FPF12045 • Rev. 1.13

#### Description

The FPF1203 / 03L / 04 / 45 are ultra-small integrated IntelliMAX<sup>™</sup> load switches with integrated P-channel switch and analog control features. Integrated slewrate control prevents inrush current and the resulting excessive voltage drop on the power rail. The input voltage range operates from 1.2 V to 5.5 V to provide power-disconnect capability for post-regulated power rails in portable and consumer products. The low shutoff current allows power designs to meet standby and off-power drain specifications.

The FPF120x are controlled by a logic input (ON pin) compatible with standard CMOS GPIO circuitry found on Field Programmable Gate Array (FPGA) embedded processors. The FPF120x are available in 0.76 mm x 0.76 mm 4-bump WLCSP.





#### **Pin Definitions**

Pin #	Name	Description	
A1	Vout	Switch output	
A2	V <sub>IN</sub>	Supply input: input to the power switch	
B1	GND	round	
B2	ON	N/OFF Control, active HIGH; FPF1203/04/45	
B2	ON	ON/OFF Control, active LOW; FPF1203L	

ON

(Bottom View)

R1

MD

R2

¥ IN

Pin 1

V<sub>OUT</sub>

GND

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Paramete	Min.	Max.	Unit	
V <sub>IN</sub>	V <sub>IN</sub> , V <sub>OUT</sub> , V <sub>ON</sub> to GND			6.0	V
I <sub>SW</sub>	Maximum Continuous Switch Current at An	bient Operating Temperature		2.2	А
PD	Power Dissipation at T <sub>A</sub> =25°C			1.0	W
T <sub>STG</sub>	Storage Temperature Range		-65	+150	°C
	Thermal Resistance, Junction-to-Ambient	1S2P with One Thermal Via <sup>(1)</sup>		110	°C/W
$\Theta_{JA}$	memai Resistance, Junction-to-Ambient	1S2P without Thermal Via <sup>(2)</sup>		95	
ESD	Electrostatic Discharge Capability <sup>(1,2)</sup>	Human Body Model, JESD22-A114	7		kV
ESD	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101	2		κV

Notes:

1. Measured using 2S2P JEDEC std. PCB.

2. Measured using 2S2P JEDEC PCB COLD PLATE Method.

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V <sub>IN</sub>	Input Voltage	1.2	5.5	V
TA	Ambient Operating Temperature -40 +		+85	°C

Symbol	I Parameter		Condition	Min.	Тур.	Max.	Unit	
Basic Op	eration					1 1		
V <sub>IN</sub>	Supply Voltage			1.2		5.5	V	
	Off Supply	FPF1203/04/45	V <sub>ON</sub> =GND, V <sub>OUT</sub> =Open, V <sub>IN</sub> =5.5 V		0.1	1.0	_	
$I_{Q(OFF)}$	Current	FPF1203L	V <sub>ON</sub> =V <sub>IN</sub> , V <sub>OUT</sub> =Open, V <sub>IN</sub> =5.5 V		1.0	2.0	μA	
_	Shutdown Current	FPF1203/04/45	V <sub>ON</sub> =GND, V <sub>OUT</sub> =GND		0.1	1.0	μA	
I <sub>SD</sub>		FPF1203L	V <sub>ON</sub> =V <sub>IN</sub> , V <sub>OUT</sub> =GND		1.2	3.0		
lq	Quiescent Current	FPF1203/04/45	I <sub>OUT</sub> =0 mA, V <sub>ON=</sub> V <sub>IN</sub> , =5.5 V					
		FPF1203L	$I_{OUT}=0$ mA, $V_{ON}=GND$ , $V_{IN}=5.5$ V		0.1	1.5	μA	
			V <sub>IN</sub> =5.5 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		45	55 <sup>(3)</sup>		
			V <sub>IN</sub> =3.3 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		55	65 <sup>(3)</sup>		
R <sub>ON</sub>	On Resistance		V <sub>IN</sub> =1.8 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		90	100 <sup>(3)</sup>	mΩ	
			V <sub>IN</sub> =1.2 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		185	220 <sup>(3)</sup>		
			$V_{IN}$ =1.8 V, $I_{OUT}$ =200 mA, $T_A$ =85°C <sup>(3)</sup>			105		
R <sub>PD</sub>	Output Discharge RPULL DOWN		V <sub>IN</sub> =3.3 V, V <sub>ON</sub> =OFF, I <sub>FORCE</sub> =20 mA, T <sub>A</sub> =25°C, FPF1204 / FPF12045		65	75	Ω	
VIH	On Input Logic HIGH Voltage		$V_{IN}$ =1.2 V to 5.5 V	1.15			V	
V <sub>IL</sub>	On Input Logic LOW Voltage		V <sub>IN</sub> =1.2 V to 5.5 V			0.65	V	
R <sub>ON_PD</sub>	Pull-Down Resistance at ON Pin		V <sub>IN</sub> =1.2 V to 5.5 V		8.3		MΩ	
I <sub>ON</sub>	On Input Leakage		V <sub>ON</sub> =V <sub>IN</sub> or GND			1	μA	
Dynamic	Characteristics							
t <sub>DON</sub>	Turn-On Delay <sup>(4)</sup>				70			
t <sub>R</sub>	V <sub>OUT</sub> Rise Time	(4)			100			
t <sub>ON</sub>	Turn-On Time <sup>(6)</sup> Turn-On Delay <sup>(4)</sup>		V <sub>IN</sub> =3.3 V, R <sub>L</sub> =10 Ω, C <sub>L</sub> =0.1 μF, T <sub>A</sub> =25°C, FPF12045	1	170		μs	
t <sub>DON</sub>				1	2			
t <sub>R</sub>	VOUT Rise Time	(4)			2			
t <sub>ON</sub>	Turn-On Time <sup>(6)</sup>				4			
t <sub>DOFF</sub>	Turn-Off Delay <sup>(4</sup>	ł,5)	V <sub>IN</sub> =3.3 V, R <sub>L</sub> =10 Ω, C <sub>L</sub> =0.1 μF, T <sub>A</sub> =25°C, FPF1203L		0.5			
t <sub>F</sub>	V <sub>OUT</sub> Fall Time <sup>(4</sup>	.,5)			2.0		μs	
t <sub>OFF</sub>	Turn-Off Time <sup>(5,</sup>	7)			2.5			
$t_{DOFF}$	Turn-Off Delay <sup>(4</sup>	1,5)			6		-	
t⊧	V <sub>OUT</sub> Fall Time <sup>(4,5)</sup>		V <sub>IN</sub> =3.3 V, R <sub>L</sub> =500 Ω, C <sub>L</sub> =0.1 μF, T <sub>A</sub> =25°C, FPF1203L		115		μs	
t <sub>OFF</sub>	Turn-Off Time <sup>(5,7)</sup>				121			
t <sub>DOFF</sub>	Turn-Off Delay <sup>(4</sup>				4.0			
t <sub>F</sub>	V <sub>OUT</sub> Fall Time <sup>(4,5)</sup> Turn-Off Time <sup>(5,7)</sup>		V <sub>IN</sub> =3.3 V, R <sub>L</sub> =10 Ω, C <sub>L</sub> =0.1 μF, T <sub>A</sub> =25°C, FPF1203		2.9		μs	
t <sub>OFF</sub>					7.3			
t <sub>DOFF</sub>	Turn-Off Delay <sup>(4,5)</sup> V <sub>OUT</sub> Fall Time <sup>(4,5)</sup> Turn-Off Time <sup>(5,7)</sup>		V <sub>IN</sub> =3.3 V, R <sub>L</sub> =500 Ω, C <sub>L</sub> =0.1 μF, T <sub>A</sub> =25°C, FPF1203		6			
t <sub>F</sub>					115		μs	
torr					121		I	

Continued on the following page...

## **Electrical Characteristics**

Unless otherwise noted,  $V_{IN}$ =1.2 V to 5.5 V and  $T_A$ =-40 to +85°C. Typical values are at  $V_{IN}$ =3.3 V and  $T_A$ =25°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
t <sub>DOFF</sub>	Turn-Off Delay <sup>(4,5)</sup>			4.0		
t <sub>F</sub>	V <sub>OUT</sub> Fall Time <sup>(4,5)</sup>	V <sub>IN</sub> =3.3 V, R <sub>L</sub> =10 Ω, C <sub>L</sub> =0.1 μF, T <sub>A</sub> =25°C, FPF1204/45 <sup>(5)</sup>		2.5		μs
t <sub>OFF</sub>	Turn-Off Time <sup>(5,7)</sup>	1 <u>,</u> 20 0, 111120 // 10		6.5		l
t <sub>DOFF</sub>	Turn-Off Delay <sup>(4,5)</sup>			6		
t <sub>F</sub>	V <sub>OUT</sub> Fall Time <sup>(4,5)</sup>	V <sub>IN</sub> =3.3 V, R <sub>L</sub> =500Ω, C <sub>L</sub> =0.1 μF, T <sub>A</sub> =25°C, FPF1204/45 <sup>(5)</sup>		11		μs
t <sub>OFF</sub>	Turn-Off Time <sup>(5,7)</sup>			17		

Notes:

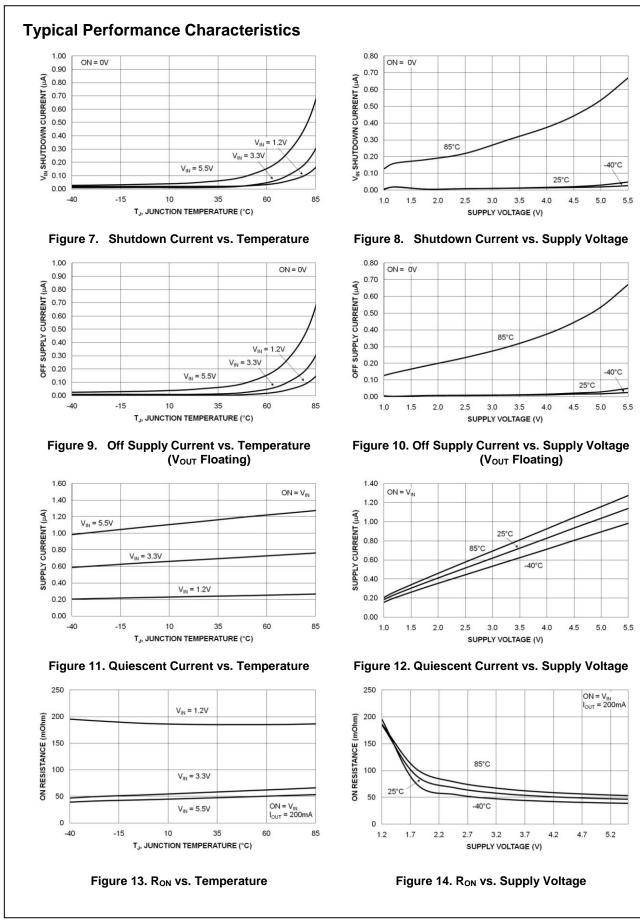
3. This parameter is guaranteed by design and characterization; not production tested.

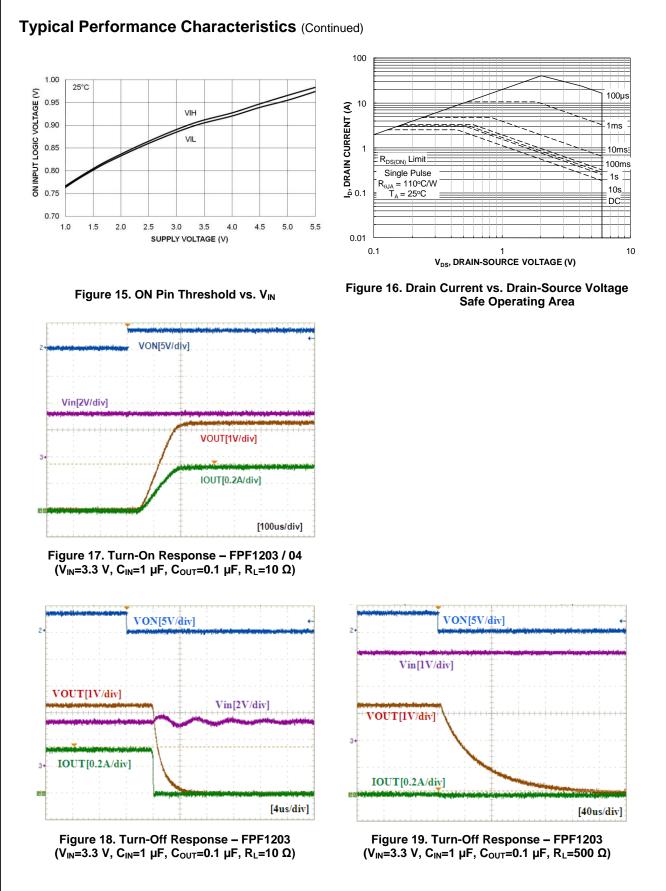
4.  $t_{DON}/t_{DOFF}/t_R/t_F$  are defined in Figure 23.

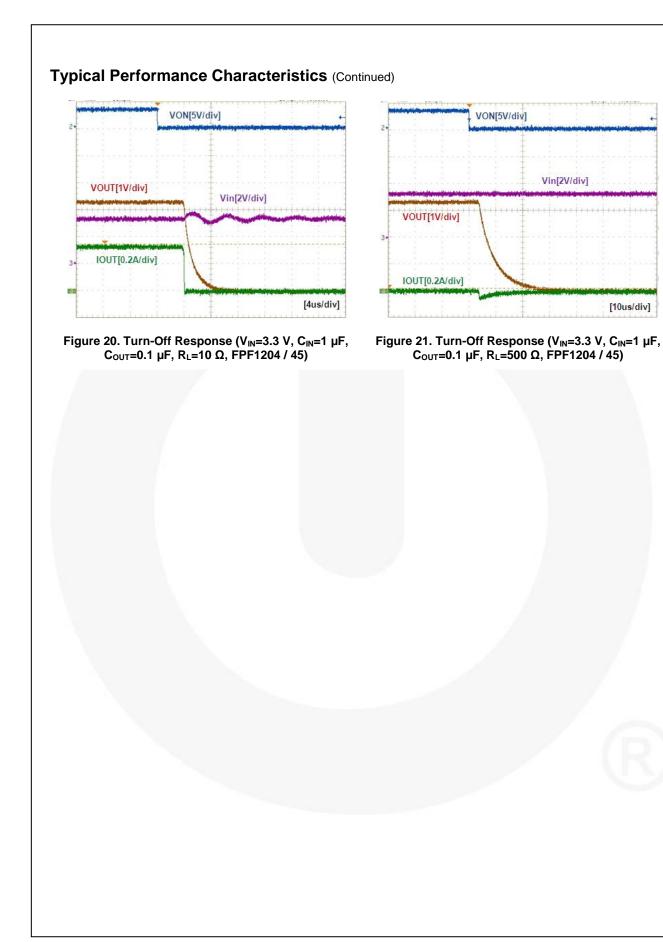
5. Output discharge enabled during off-state.

6.  $t_{ON}=t_R + t_{DON}$ 

7. t<sub>OFF</sub>=t<sub>F</sub> + t<sub>DOFF</sub>.







#### **Operation and Application Description**

The FPF1203 / 03L / 04 / 045 are low-R<sub>ON</sub> P-channel load switches with controlled turn-on. The core of each device is a 55 m $\Omega$  P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.2 to 5.5 V.

The FPF1204 / 45 contain a 65  $\Omega$  on-chip load resistor for quick output discharge when the switch is turned off.

The FPF12045 features a faster  $V_{OUT}$  Rise Time of 5 µs.

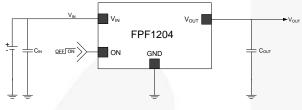


Figure 22. Typical Application

#### **Input Capacitor**

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor or short-circuit, a capacitor must be placed between the V<sub>IN</sub> and GND pins. A 1  $\mu$ F ceramic capacitor, C<sub>IN</sub>, placed close to the pins is usually sufficient. Higher-value C<sub>IN</sub> can be used to reduce the voltage drop in higher-current applications.

#### **Output Capacitor**

A 0.1  $\mu$ F capacitor, C<sub>OUT</sub>, should be placed between the V<sub>OUT</sub> and GND pins. This capacitor prevents parasitic board inductance from forcing V<sub>OUT</sub> below GND when the switch is on. C<sub>IN</sub> greater than C<sub>OUT</sub> is highly recommended. C<sub>OUT</sub> greater than C<sub>IN</sub> can cause V<sub>OUT</sub> to exceed V<sub>IN</sub> when the system supply is removed. This could result in current flow through the body diode from V<sub>OUT</sub> to V<sub>IN</sub>.

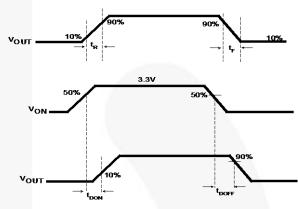


Figure 23. Timing Diagram for FPF1203/4/045

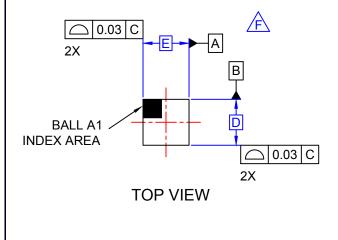
#### **Board Layout**

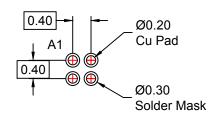
For best performance, traces should be as short as possible. To be most effective, input and output capacitors should be placed close to the device to minimize the effect of parasitic trace inductance on normal and short-circuit operation. Using wide traces or large copper planes for all pins (VIN, VOUT, ON, and GND) minimizes the parasitic electrical effects and the case-ambient thermal impedance. However, the VOUT pin should not connect directly to the battery source due to the discharge mechanism of the load switch.

The table below pertains to the Packaging information on the following page.

#### **Product Dimensions**

D	E	X	Y
760 μm ± 30 μm	760 μm ± 30 μm	0.180 mm± 0.018 µm	0.180 mm± 0.018 μm

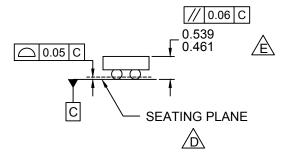




0.292±0.018

0.208±0.021

**RECOMMENDED LAND PATTERN** (NSMD PAD TYPE)



SIDE VIEWS

NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.
- D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- /E.PACKAGE NOMINAL HEIGHT IS 500 MICRONS ±39 MICRONS (461-539 MICRONS).

## F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

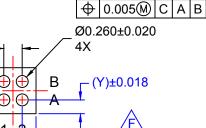
G. DRAWING FILNAME: MKT-UC004AFrev2.



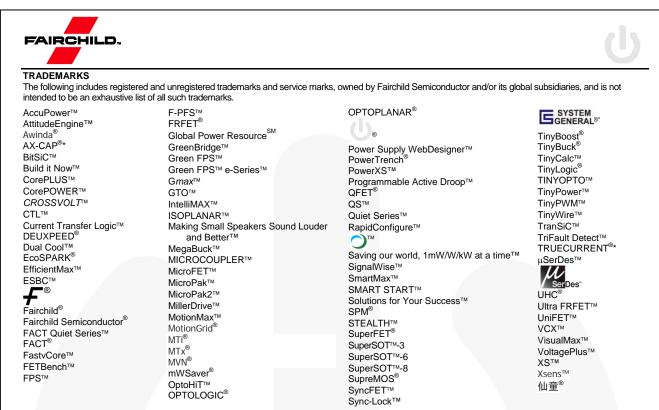
**BOTTOM VIEW** 

0.40

0.40



(X)±0.018



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Definition of Terms	Definition of Terms					
Datasheet Identification	Product Status	Definition				
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.				
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.				
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.				
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